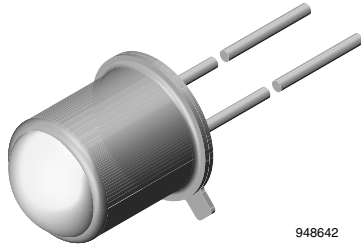


**Silicon PIN Photodiode, RoHS Compliant**



948642

**DESCRIPTION**

BPW24R is a high sensitive silicon planar photodiode in a standard TO-18 hermetically sealed metal case with a glass lens.

A precise alignment of the chip gives a good coincidence of mechanical and optical axes. The device features a low capacitance and high speed even at low supply voltages.

**FEATURES**

- Package type: leaded
- Package form: TO-18
- Dimensions (in mm): Ø 4.7
- Radiant sensitive area (in mm<sup>2</sup>): 0.78
- High photo sensitivity
- High radiant sensitivity
- Suitable for visible and near infrared radiation
- Fast response times
- Angle of half sensitivity:  $\varphi = \pm 12^\circ$
- Hermetically sealed package
- Cathode connected to package
- Central chip alignment
- Lead (Pb)-free component in accordance with RoHS 2002/95/EC and WEEE 2002/96/EC



**RoHS**  
COMPLIANT

**APPLICATIONS**

- High speed photo detector

<b>PRODUCT SUMMARY</b>			
COMPONENT	$I_{ra}$ (µA)	$\varphi$ (deg)	$\lambda_{0.5}$ (nm)
BPW24R	60	$\pm 12$	600 to 1050

**Note**

Test condition see table “Basic Characteristics”

<b>ORDERING INFORMATION</b>			
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM
BPW24R	Bulk	MOQ: 1000 pcs, 1000 pcs/bulk	TO-18

**Note**

MOQ: minimum order quantity

<b>ABSOLUTE MAXIMUM RATINGS</b>				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		$V_R$	60	V
Power dissipation	$T_{amb} \leq 25^\circ\text{C}$	$P_V$	210	mW
Junction temperature		$T_j$	125	°C
Operating temperature range		$T_{amb}$	- 40 to + 125	°C
Storage temperature range		$T_{stg}$	- 40 to + 125	°C
Soldering temperature	$t \leq 5$ s	$T_{sd}$	260	°C
Thermal resistance junction/ambient	Connected with Cu wire, 0.14 mm <sup>2</sup>	$R_{thJA}$	350	K/W

**Note**

$T_{amb} = 25^\circ\text{C}$ , unless otherwise specified

<b>BASIC CHARACTERISTICS</b>						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Breakdown voltage	$I_R = 100 \mu A, E = 0$	$V_{(BR)}$	60	200		V
Reverse dark current	$V_R = 50 V, E = 0$	$I_{ro}$		2	10	nA
Diode capacitance	$V_R = 0 V, f = 1 MHz, E = 0$	$C_D$		11		pF
	$V_R = 5 V, f = 1 MHz, E = 0$	$C_D$		3.8		pF
	$V_R = 20 V, f = 1 MHz, E = 0$	$C_D$		2.5		pF
Open circuit voltage	$E_e = 1 mW/cm^2, \lambda = 950 nm$	$V_o$		450		mV
Temperature coefficient of $V_o$	$E_e = 1 mW/cm^2, \lambda = 950 nm$	$TK_{V_o}$		-2		mV/K
Short circuit current	$E_e = 1 mW/cm^2, \lambda = 950 nm$	$I_k$		55		$\mu A$
Temperature coefficient of $I_k$	$E_A = 1 klx$	$TK_{I_k}$		0.1		%/K
Reverse light current	$E_e = 1 mW/cm^2, \lambda = 950 nm, V_R = 20 V$	$I_{ra}$	45	60		$\mu A$
Absolute Spectral Sensitivity	$V_R = 5 V, \lambda = 870 nm$	$s(\lambda)$		0.60		A/W
	$V_R = 5 V, \lambda = 900 nm$	$s(\lambda)$		0.55		A/W
Angle of half sensitivity		$\phi$		$\pm 12$		deg
Wavelength of peak sensitivity		$\lambda_p$		900		nm
Range of spectral bandwidth		$\lambda_{0.5}$		600 to 1050		nm
Rise time	$V_R = 20 V, R_L = 50 \Omega, \lambda = 820 nm$	$t_r$		7		ns
Fall time	$V_R = 20 V, R_L = 50 \Omega, \lambda = 820 nm$	$t_f$		7		ns

**Note**

$T_{amb} = 25 \text{ }^\circ C$ , unless otherwise specified

**BASIC CHARACTERISTICS**

$T_{amb} = 25 \text{ }^\circ C$ , unless otherwise specified

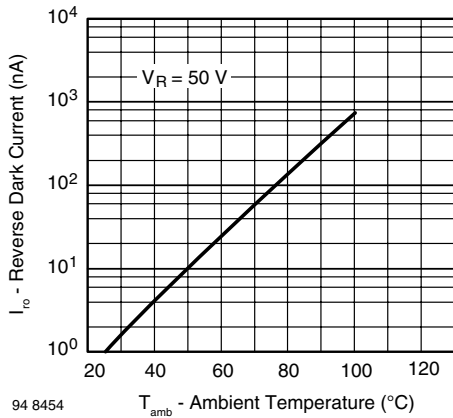


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

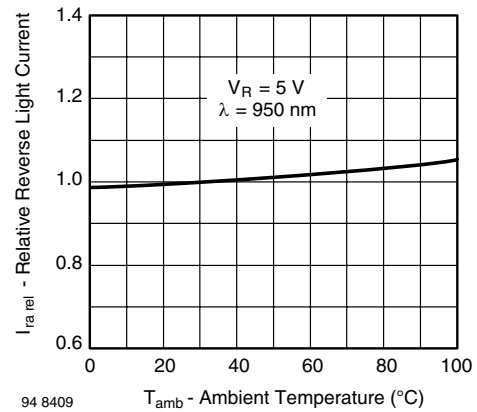


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

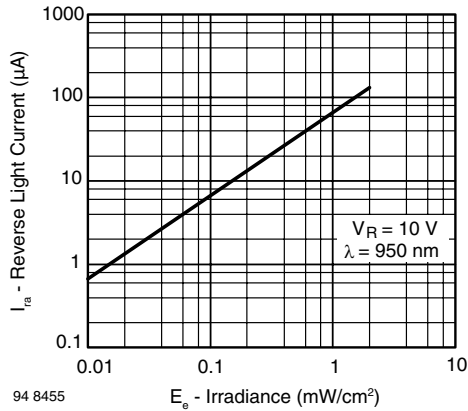


Fig. 3 - Reverse Light Current vs. Irradiance

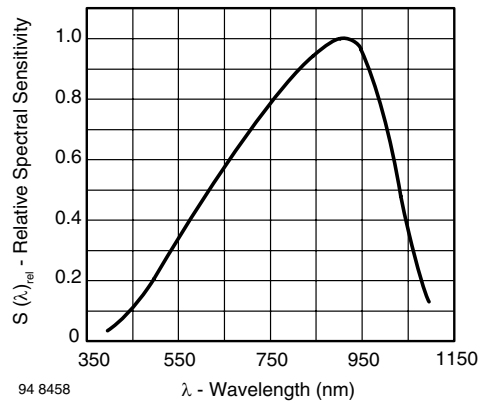


Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

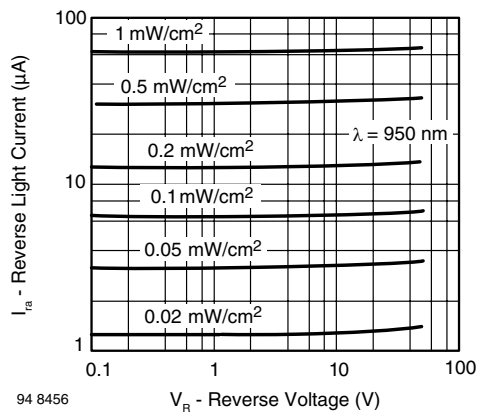


Fig. 4 - Reverse Light Current vs. Reverse Voltage

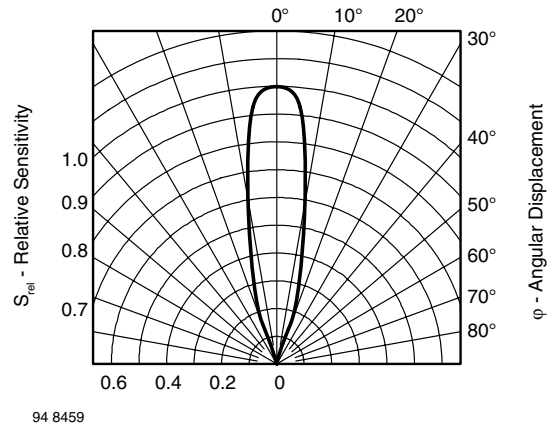


Fig. 7 - Relative Radiant Sensitivity vs. Angular Displacement

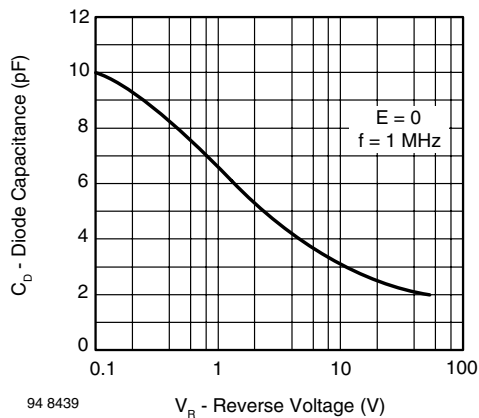
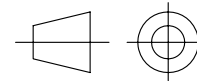
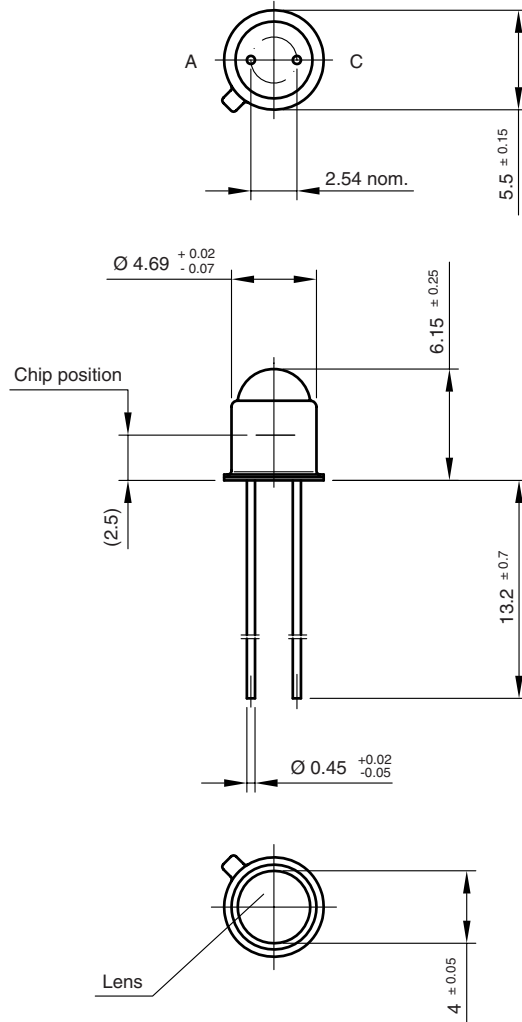


Fig. 5 - Diode Capacitance vs. Reverse Voltage



**PACKAGE DIMENSIONS** in millimeters



technical drawings  
according to DIN  
specifications

Drawing-No.: 6.503-5022.02-4

Issue: 1; 24.08.98

14487



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